



DLD101

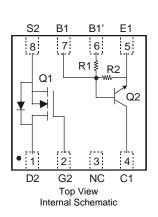
LINEAR MODE CURRENT SINK LED DRIVER

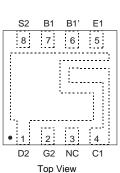
Features

- Primarily Designed for Driving LED/s for Illumination, Signage and Backlighting Applications
- Ideally Suited for Linear Mode Constant Current Applications
- V_{BE} Referenced Current Sink Circuit
- Includes:
 - N-Channel Enhancement Mode MOSFET (Q1)
 - Base Accessible Pre-Biased Transistor (Q2)
- High Voltage Capable (50V)
- Small Form Factor Surface Mount Package
- High Dissipation Capability
- Low Thermal Resistance
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

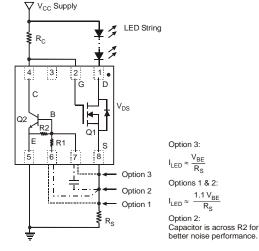
Mechanical Data

- Case: DFN3030D-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 7
- Ordering Information: See Page 7
- Weight: 0.0172 grams (approximate)





Package Pin-Out Configuration



Typical Application Circuit for Linear Mode Current Sink LED Driver

Maximum Ratings: (Q1) @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Drain Source Voltage		V _{DSS}	100	V
Gate-Source Voltage		V _{GSS}	±20	V
Drain Current (Note 3)	T _A = 25°C T _A = 70°C	I _D	1.0 0.8	А
Drain Current (Note 3)	Pulsed	I _{DM}	3.0	А
Body-Diode Continuous Current (Note 3)		Is	1.0	А

Maximum Ratings: (Q2) @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage	V _{CC}	50	V
Input Voltage	V _{IN}	-5 to +30	V
Output Current (DC)	lo	100	mA

Notes: 1. No purposefully added lead.

2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.



Thermal Characteristics – Total Device

Characteristic	Symbol	Value	Unit
Power Dissipation @T _A = 25°C	P _D	0.7 (Note 3) 0.9 (Note 4) 1.4 (Note 5)	W
Thermal Resistance Junction to Ambient $@T_A = 25^{\circ}C$	R _{0JA}	See Figure 1 (Notes 3, 4, & 5)	°C/W
Thermal Resistance Junction to Case $@T_A = 25^{\circ}C$	R _{θJC}	See Figure 2 (Notes 3, 4, & 5)	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

 Part mounted on FR-4 substrate PC board, with minimum recommended pad layout (see page 6).
Part mounted on FR-4 substrate PC board, 2oz Copper with 6 mm2 Cu Area, MOSFET element activated.
Part mounted on FR-4 substrate PC board, 2oz Copper with 35 mm2 Cu Area, MOSFET element activated. Notes:

Electrical Characteristics: (Q1) @T_A = 25°C unless otherwise specified

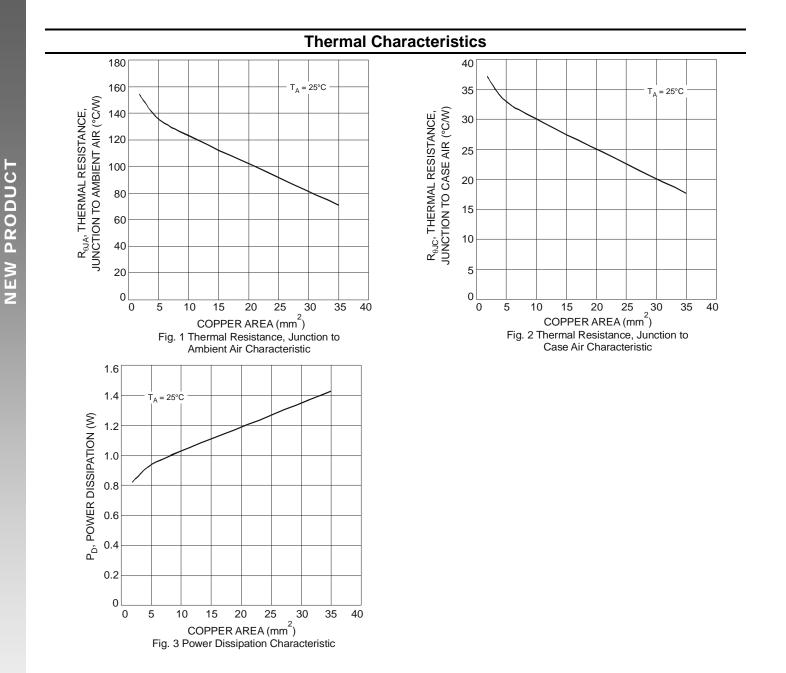
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV _{DSS}	100		_	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	—		1	μΑ	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	V _{GS(th)}	2.0	_	4.1	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance				0.85	Ω	V _{GS} = 10V, I _D = 1.5A	
Static Dialit-Source Off-Resistance	R _{DS} (ON)	_		0.99	12	$V_{GS} = 6V, I_D = 1A$	
Forward Transconductance	g fs	_	0.9		S	$V_{DS} = 15V, I_D = 1A$	
Diode Forward Voltage	V _{SD}	_	0.89	1.1	V	V _{GS} = 0V, I _S = 1.5A	
DYNAMIC CHARACTERISTICS		_		_	_		
Input Capacitance	Ciss	_	129	_	pF		
Output Capacitance	Coss	—	14	_	pF	V _{DS} = 50V, V _{GS} = 0V f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	8	_	pF		
SWITCHING CHARACTERISTICS		_		_	_		
Total Gate Charge	Qg	_	3.4				
Gate-Source Charge	Q _{gs}	_	0.9		nC	$V_{DS} = 50V, V_{GS} = 10V, I_D = 1A$	
Gate-Drain Charge	Q _{gd}	—	1	_			
Turn-On Delay Time	t _{d(on)}		7.9				
Rise Time	tr	_	11.4	_	ns	$V_{GS} = 50V, V_{DS} = 10V,$	
Turn-Off Delay Time	t _{d(off)}		14.3		115	$I_D = 1A, R_G \approx 6\Omega$	
Fall Time	tf		9.6				

Electrical Characteristics: (Q2) @T_A = 25°C unless otherwise specified

Characteristic (Note 6)	Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage	V _{I(off)}	0.4	-	-	V	$V_{CC} = 5V, I_{O} = 100 \mu A$
input voltage	V _{I(on)}	-	-	1.5	V	$V_{CC} = 0.3V, I_{O} = 5mA$
Output Voltage	V _{O(on)}	-	0.05	0.3	V	$I_0/I_1 = 5mA/0.25mA$
Output Current	I _{O(off)}	-	-	0.5	μΑ	$V_{CC} = 50V, V_1 = 0V$
DC Current Gain	G ₁	80	-	-	-	$V_0 = 5V, I_0 = 10mA$
Input Resistance	R ₁	3.2	4.7	6.2	kΩ	-
Resistance Ratio	R ₂ /R ₁	8	10	12	-	-
Transition Frequency	fT	-	260	-	MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz

Notes: 6. Short duration pulse test used to minimize self-heating effect.







10

9 8

7 6

5

4

3

2

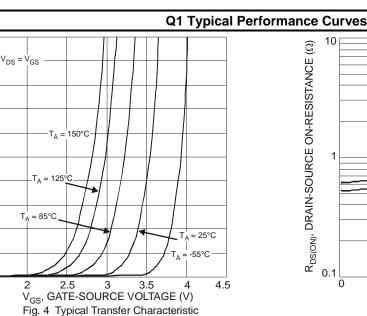
1

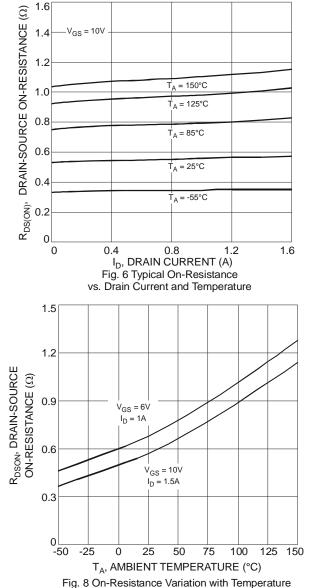
0

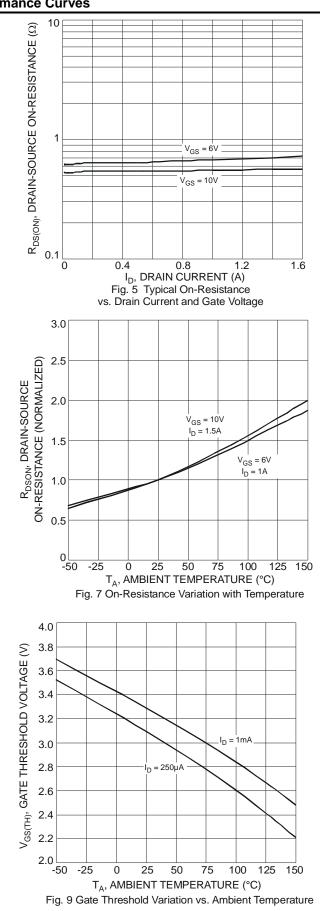
1.5

ID, DRAIN CURRENT (A)

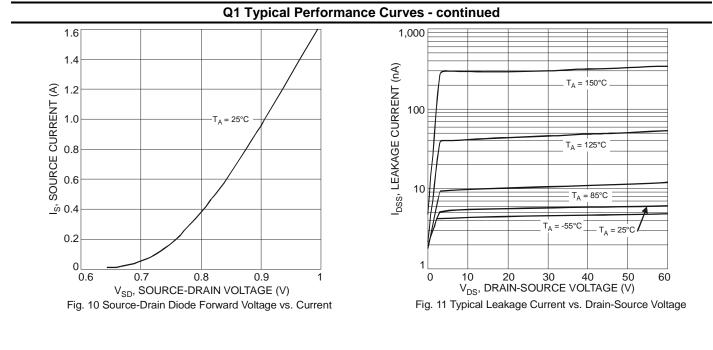
NEW PRODUCT







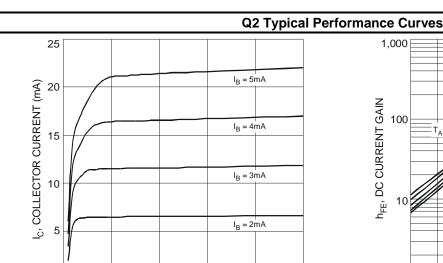




1,000

100

1



I_B = 1mA 1 2 3 4 V_{CE}, COLLECTOR-EMITTER VOLTAGE (V) Fig. 12 Typical Collector Current vs. Collector-Emitter Voltage

h_{FE}, DC CURRENT GAIN Г_А = 85°С = 25°C = -55°C 10

T_A = 150°C

0.1 10 50 I_C, COLLECTOR CURRENT (mA) Fig. 13 Typical DC Current Gain vs. Collector Current

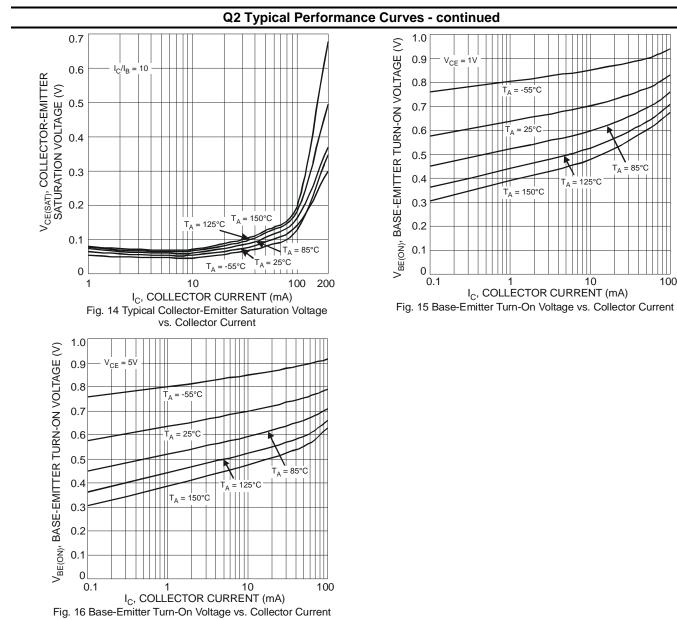
DLD101

0

0

5







Typical Application Circuit

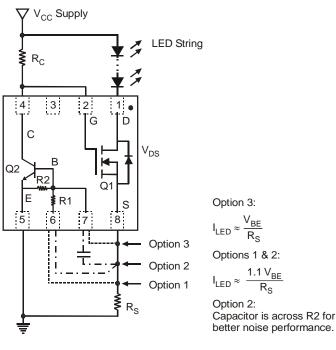


Fig. 12 Typical Application Circuit for Linear Mode Current Sink LED Driver

The DLD101 has been designed primarily for solid state lighting applications, to be used as a current sink circuit solution for LEDs. It features a N-channel MOSFET capable of 1A drive current and a prebiased NPN transistor (which allows direct connection to the base, or via a series base resistor).

Figure 12 shows a typical application circuit diagram for driving an LED or string of LEDs. Note that the pre-biased transistor (Q2) has the option of bypassing the series base resistor by connecting directly to pin 7. The N-MOSFET (Q1) is configured as a V_{BE} referenced current sink and is biased on by R_C. The current passed through the LED string, MOSFET and source resistor, develops a voltage across R_S that provides a bias to the NPN transistor. Consideration of the expected linear mode power dissipation must be factored into the design, with respect to the DLD101's thermal resistance.

 $V_{DS} = V_{CC} - V_{F \ LED \ String} - V_{RS}$ $P_{Q1} = V_{DS} * I_{LED \ String}$

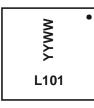
PWM dimming functionality can be effected by either driving the NPN base via an additional resistor (thereby overriding the feedback from R_S) or by pulling the gate of the MOSFET down by direct connection. The PWM control pulse stream can be provided by a micro-controller or simple 555 based circuitry.

Ordering Information (Note 7)

Part Number	Case	Packaging
DLD101-7	DFN3030D-8	3000/Tape & Reel

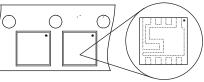
Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



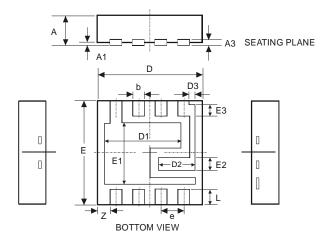
L101 = Product marking code YYWW = Date code marking YY = Last digit of year (ex: 10 for 2010) WW = Week code (01 to 53)





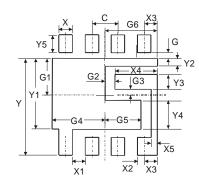


Package Outline Dimensions



DFN3030D-8							
Dim	Min	Max	Тур	Dim	Min	Max	Тур
Α	0.570	0.630	0.600	е	-	-	0.650
A1	0	0.050	0.020	Е	2.950	3.075	3.000
A3	-	-	0.150	E1	1.800	2.000	1.900
b	0.290	0.390	0.340	E2	0.290	0.490	0.390
D	2.950	3.075	3.000	E3	0.175	0.375	0.275
D1	2.175	2.375	2.275	L	0.300	0.40	0.350
D2	0.980	1.180	1.080	Z	-	-	0.355
D3 0.105 0.305 0.205							
All Dimensions in mm							

Suggested Pad Layout



Dimensions	Value (in mm)	Dimensions	Value (in mm)
С	0.650	X2	0.220
G	0.150	X3	0.375
G1	0.950	X4	1.080
G2	0.270	X5	0.150
G3	0.135	Y	2.600
G4	1.350	Y1	1.900
G5	0.925	Y2	0.150
G6	1.350	Y3	0.390
Х	0.440	Y4	0.815
X1	0.210	Y5	0.550



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2010, Diodes Incorporated

www.diodes.com